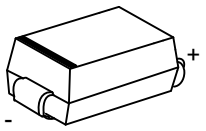
ES2D

DIODE

SURFACE MOUNT SUPER FAST RECTIFIER



SMB
(JEDEC DO-214AA)

■ DESCRIPTION

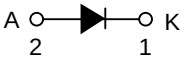
The UTC **ES2D** is a surface mount super fast rectifier, it uses UTC's advanced technology to provide customers with high forward surge current and low reverse leakage, etc.

The UTC **ES2D** is suitable for surface mounted applications.

■ FEATURES

* Low reverse leakage
* High forward surge current capability

■ SYMBOL



■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment		Packing
Lead Free	Halogen Free		1	2	
ES2DL-SMB-R	ES2DG-SMB-R	SMB	K	A	Tape Reel

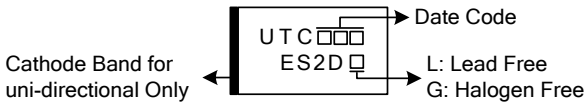
Note: Pin Assignment: A: Anode K: Cathode

ES2DG-SMB-R

(1)Packing Type
(2)Package Type
(3)Green Package

(1) R: Tape Reel
(2) SMB: SMB
(3) G: Halogen Free and Lead Free, L: Lead Free

■ MARKING



■ ABSOLUTE MAXIMUM RATINGS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
Repetitive Peak Reverse Voltage	V_{RRM}	200	V
RMS Voltage	V_{RMS}	140	V
DC Blocking Voltage	V_{DC}	200	V
Average Forward Rectified Current at T_L=55°C	$I_{(AV)}$	2.0	A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	60	A
Junction Temperature	T_J	-55 ~ +150	°C
Storage Temperature	T_{STG}	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient (Note 3)	θ_{JA}	34	°C/W

■ ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Instantaneous Forward Voltage	V_F	I_F=2.0A			0.95	V
DC Reverse Current at Rated DC Blocking Voltage	I_R	T_A=25°C			5	μA
		T_A=100°C			150	μA
Reverse Recovery Time (Note 1)	t_{rr}				35	ns
Junction Capacitance (Note 2)	C_J				25	pF

Notes: 1. Reverse recovery condition I_F=0.5A, I_R=1.0A, I_{rr}=0.25A.
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
3. P.C.B. mounted with 0.2×0.2” (5.0×5.0mm) copper pad areas.

■ TYPICAL CHARACTERISTICS